

2N4856A, 2N4857A, 2N4858A, 2N4859A, 2N4860A, 2N4861A

N-Channel Silicon Junction Field-Effect Transistor

- Choppers
- Commutators
- Analog Switches

Absolute maximum ratings at $T_A = 25^\circ\text{C}$

| | 2N4856A, 2N4857A, 2N4858A | 2N4859A, 2N4860A, 2N4861A |
|---------------------------------|---------------------------|---------------------------|
| Reverse Gate Source Voltage | - 40 V | - 30 V |
| Reverse Gate Drain Voltage | - 40 V | - 30 V |
| Continuous Device Dissipation | 1.8 W | 1.8 W |
| Continuous Forward Gate Current | 50 mA | 50 mA |
| Power Derating | 10 mA/°C | 10 mA/°C |

At 25°C free air temperature:

| Static Electrical Characteristics | | 2N4856A 2N4859A | | 2N4857A 2N4860A | | 2N4858A 2N4861A | | Process NJ132 | |
|--|---------------|--------------------|--------------|--------------------|-------------|--------------------|------------|---------------|--|
| | | Min | Max | Min | Max | Min | Max | Unit | Test Conditions |
| Gate Source Breakdown Voltage 2N4856A, 2N4857A, 2N4858A | $V_{(BR)GSS}$ | | - 40 | | - 40 | | - 40 | V | $I_G = -1\mu\text{A}, V_{DS} = 0\text{V}$ |
| Gate Source Breakdown Voltage 2N4859A, 2N4860A, 2N4861A | $V_{(BR)GSS}$ | | - 30 | | - 30 | | - 30 | V | $I_G = -1\mu\text{A}, V_{DS} = 0\text{V}$ |
| Gate Reverse Current 2N4856A, 2N4857A, 2N4858A | I_{GSS} | | - 250 | | - 250 | | - 250 | pA | $V_{GS} = -20\text{V}, V_{DS} = 0\text{V}$ |
| | | | - 500 | | - 500 | | - 500 | nA | $V_{GS} = -20\text{V}, V_{DS} = 0\text{V}$ $T_A = 150^\circ\text{C}$ |
| Gate Reverse Current 2N4859A, 2N4860A, 2N4861A | I_{GSS} | | - 250 | | - 250 | | - 250 | pA | $V_{GS} = -15\text{V}, V_{DS} = 0\text{V}$ |
| | | | - 500 | | - 500 | | - 500 | nA | $V_{GS} = -15\text{V}, V_{DS} = 0\text{V}$ $T_A = 150^\circ\text{C}$ |
| Gate Source Cutoff Voltage | $V_{GS(OFF)}$ | - 4 | - 10 | - 2 | - 6 | - 0.8 | - 4 | V | $V_{DS} = 15\text{V}, I_D = 0.5\text{nA}$ |
| Drain Saturation Current (Pulsed) | I_{DSS} | 50 | | 20 | 100 | 8 | 80 | mA | $V_{DS} = 15\text{V}, V_{GS} = 0\text{V}$ |
| Drain Cutoff Current | $I_{D(OFF)}$ | | 250 | | 250 | | 250 | pA | $V_{DS} = 15\text{V}, V_{GS} = -10\text{V}$ |
| | | | 500 | | 500 | | 500 | nA | $V_{DS} = 15\text{V}, V_{GS} = -10\text{V}$ $T_A = 150^\circ\text{C}$ |
| Drain Source ON Voltage | $V_{DS(ON)}$ | | 0.75 (20) | | 0.5 (10) | | 0.5 (5) | V (mA) | $V_{GS} = 0\text{V}, I_D = ()$ |

Dynamic Electrical Characteristics

| | | | | | | | | | | |
|--|--------------|--|----|--|-----|--|-----|----------|--|-------------------|
| Common Source ON Resistance | $r_{ds(on)}$ | | 25 | | 40 | | 60 | Ω | $V_{GS} = 0\text{V}, I_D = 0\text{A}$ | $f = 1\text{kHz}$ |
| Common Source Input Capacitance | C_{iss} | | 10 | | 10 | | 10 | pF | $V_{DS} = 0\text{V}, V_{GS} = -10\text{V}$ | $f = 1\text{MHz}$ |
| Common Source Reverse Transfer Capacitance | C_{rss} | | 4 | | 3.5 | | 3.5 | pF | $V_{DS} = 0\text{V}, V_{GS} = -10\text{V}$ | $f = 1\text{MHz}$ |

Switching Characteristics

| | | | | | | | | | |
|---------------------|--------------|--|---------------------|--|--------------------|--|-------------------|-------------------|---|
| Turn ON Delay Time | $t_{d(on)}$ | | 5 (20) [-10] | | 6 (10) [-6] | | 8 (5) [-4] | ns (mA) [V] | $V_{DD} = 10\text{V}, V_{GS} = 0\text{V}$ $I_{D(ON)} = ()$ $V_{GS(OFF)} = []$ (2N4856A, 2N4859A) $R_L = 464\Omega$ (2N4857A, 2N4860A) $R_L = 953\Omega$ (2N4858A, 2N4861A) $R_L = 1910\Omega$ |
| Rise Time | t_r | | 3 (20) [-10] | | 4 (10) [-6] | | 8 (5) [-4] | ns (mA) [V] | |
| Turn OFF Delay Time | $t_{d(off)}$ | | 25 (20) [-10] | | 40 (10) [-6] | | 80 (5) [-4] | ns (mA) [V] | |

TO-18 Package

See Section G for Outline Dimensions

Pin Configuration

1 Source, 2 Drain, 3 Gate & Case

Surface Mount

SMP4856A, SMP4857A, SMP4858A,
SMP4859A, SMP4860A, SMP4861A



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